NSN 5962-01-420-9601

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-420-9601

Body Length:
0.358 inches
Body Width:
0.358 inches
Body Height:
0.100 inches
Maximum Power Dissipation Rating:
550.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Hermetically sealed and burn in and programmable and positive outputs and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
G-2 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:

NSN 5962-01-420-9601

Memory Microcircuit - Page 2 of 2

Demilitarization:

No

Fiig:

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